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Form PTO-1449 (Modified)	Atty. Docket No. 71493-1041	Serial No. 10/025,866
FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	Applicant John White	
(Use several sheets if necessary)	Filing Date December 26, 2001	Group 2881

REFERENCE DESIGNATION U.S. PATENT DOCUMENTS

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FOREIGN PATENT DOCUMENTS

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OTHER ART (including Author, Title, Date, Pertinent Pages, Etc.)

	OTHER ART (including Author, Title, Date, Pertinent Pages, Etc.)					
M AC	Zah Chung-En et al: "High-Performance Uncooled 1.3µm Al <sub>x</sub> Ga <sub>1-x-y</sub> As/InP Strained-Layer Quantum-Well Lasers for Subscriber Loop Applications", IEEE Journal of Quantum Electronics, February 1994, vol. 30, no. 2, pages 511-523					
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**EXAMINER:** 

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